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	APPLICANT	
	Ravi K. Laxmann, et al.	
	FILING DATE	GROUP
	March 17, 2001	1762

U.S. PATENT DOCUMENTS

EXAMINER INITIAL		PATENT NUMBER	ISSUE DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE
SA	AA	5,204,134	4/20/1993	Girsh			
	AB	5,536,323	7/16/1996	Kirlin, et al.			
	AC	5,711,816	1/27/1998	Kirlin, et al.			
	AD	6,022,812	2/8/2000	Smith, et al.			
	AE	6,048,804	4/11/2000	Smith, et al.			
	AF	6,054,206	4/25/2000	Mountsier			
SA	AG	6,171,945	1/29/2001	Mandal, et al.			

FOREIGN PATENT DOCUMENTS

		DOCUMENT NUMBER	PUBLICATION DATE	COUNTRY	CLASS	SUBCLAS S	TRANSLATION YES	NO
							X (abstrac t only)	

OTHER DOCUMENTS (Including Author, Title, Journal-Date, Page Number, Etc.)

SB	AH	Tadashi Nakano, et al., J. Electrochem. Soc., Vol. 142, No. 4, April 1995, "EFFECTS OF SI -C BOND CONTENT ON FILM PROPERTIES OF ORGANIC SPIN-ON GLASS", pgs. 1303-1308.					
SA	AI	Lu, et al., Mat. Res. Soc. Sym. Proc., "LOW DIELECTRIC CONSTANT MATERIALS-SYNTHESIS AND APPLICATIONS IN MICROELECTRONICS", April 17-19, San Francisco, CA, 1995, pp. 267-272.					
SA	AJ	D.A. Saulys, et al., Mat. Res. Soc. Symp. Prec. Vol. 447, "POINT-OF-USE SILICON SOURCES FOR CVD", 1997, pgs. 139-143.					

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EXAMINER	DATE CONSIDERED
	W/17/03

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